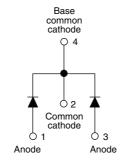


Vishay Semiconductors

# Ultrafast Rectifier, 2 x 3 A FRED Pt®





PRODUCT SUMMARY						
Package	D-PAK (TO-252AA)					
I <sub>F(AV)</sub>	2 x 3 A					
$V_{R}$	200 V					
V <sub>F</sub> at I <sub>F</sub>	1.0 V					
t <sub>rr</sub> typ.	See Recovery table					
T <sub>J</sub> max.	175 °C					
Diode variation	Common cathode					

### **FEATURES**

- · Ultrafast recovery time
- Low forward voltage drop



- 175 °C operating junction temperature
- Compliant to RoHS Directive 2002/95/EC
- Meets MSL level 1, per J-STD-020, LF maximum peak of 260 °C

### **DESCRIPTION/APPLICATIONS**

VS-MURD620CTPbF is the state of the art ultrafast recovery rectifier specifically designed with optimized performance of forward voltage drop and ultrafast recovery time.

The planar structure and the platinum doped life time control, guarantee the best overall performance, ruggedness and reliability characteristics.

These devices are intended for use in the output rectification stage of SMPS, UPS, DC/DC converters as well as freewheeling diode in low voltage inverters and chopper motor drives.

Their extremely optimized stored charge and low recovery current minimize the switching losses and reduce over dissipation in the switching element and snubbers.

ABSOLUTE MAXIMUM RATINGS							
PARAMETER	SYMBOL	TEST CONDITIONS	MAX.	UNITS			
Peak repetitive reverse voltage	$V_{RRM}$		200	V			
Average rectified forward current per device	I <sub>F(AV)</sub>	Total device, rated V <sub>R</sub> , T <sub>C</sub> = 146 °C	6				
Non-repetitive peak surge current	I <sub>FSM</sub>		50	Α			
Peak repetitive forward current per diode	I <sub>FM</sub>	Rated V <sub>R</sub> , square wave, 20 kHz, T <sub>C</sub> = 146 °C	6				
Operating junction and storage temperatures	T <sub>J</sub> , T <sub>Stg</sub>		- 65 to 175	°C			

<b>ELECTRICAL SPECIFICATIONS</b> (T <sub>J</sub> = 25 °C unless otherwise specified)							
PARAMETER	SYMBOL	TEST CONDITIONS	MIN.	TYP.	MAX.	UNITS	
Breakdown voltage, blocking voltage	V <sub>BR</sub> , V <sub>R</sub>	Ι <sub>R</sub> = 100 μΑ	200	-	-		
		I <sub>F</sub> = 3 A	-	-	1.0		
Forward voltage	V <sub>F</sub>	I <sub>F</sub> = 3 A, T <sub>J</sub> = 125 °C	-	-	0.96	V	
		I <sub>F</sub> = 6 A	-	-	1.2		
		I <sub>F</sub> = 6 A, T <sub>J</sub> = 125 °C	-	-	1.13		
		V <sub>R</sub> = V <sub>R</sub> rated	-	-	5		
Reverse leakage current	I <sub>R</sub>	T <sub>J</sub> = 125 °C, V <sub>R</sub> = V <sub>R</sub> rated	25		250	- μΑ	
Junction capacitance	C <sub>T</sub>	V <sub>R</sub> = 200 V	-	12	-	pF	
Series inductance	L <sub>S</sub>	Measured lead to lead 5 mm from package body	-	8.0	-	nH	

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# VS-MURD620CTPbF

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<b>DYNAMIC RECOVERY CHARACTERISTICS</b> (T <sub>J</sub> = 25 °C unless otherwise specified)							
PARAMETER	SYMBOL	TEST CO	MIN.	TYP.	MAX.	UNITS	
Reverse recovery time		I <sub>F</sub> = 1.0 A, dI <sub>F</sub> /dt =	50 A/μs, V <sub>R</sub> = 30 V	-	-	35	
	4	I <sub>F</sub> = 0.5 A, I <sub>R</sub> = 1.0 A, I <sub>REC</sub> = 0.25 A		-	-	25	ns
	t <sub>rr</sub>	T <sub>J</sub> = 25 °C	$I_F = 3 \text{ A}$ $dI_F/dt = 200 \text{ A/}\mu\text{s}$ $V_R = 160 \text{ V}$	-	19	-	115
		T <sub>J</sub> = 125 °C		-	26	-	
Peak recovery current	I <sub>RRM</sub>	T <sub>J</sub> = 25 °C		-	3.1	-	^
		T <sub>J</sub> = 125 °C		=	4.6	-	Α
Reverse recovery charge	Q <sub>rr</sub>	T <sub>J</sub> = 25 °C		-	30	-	20
		T <sub>J</sub> = 125 °C		-	60	-	nC

THERMAL - MECHANICAL SPECIFICATIONS						
PARAMETER	SYMBOL	TEST CONDITIONS	MIN.	TYP.	MAX.	UNITS
Maximum junction and storage temperature range	T <sub>J</sub> , T <sub>Stg</sub>		- 65	-	175	°C
Thermal resistance, junction to case per leg	R <sub>thJC</sub>		-	-	9.0	
Thermal resistance, junction to ambient per leg	R <sub>thJA</sub>		-	-	80	°C/W
Thermal resistance, case to heatsink	R <sub>thCS</sub>	Mounting surface, flat, smooth and greased	=	-	-	
Waight			-	0.3	-	g
Weight			-	0.01	-	oz.
Mounting torque			6.0 (5.0)	-	12 (10)	kgf · cm (lbf · in)
Marking device		Case style D-PAK	MURD620CT			





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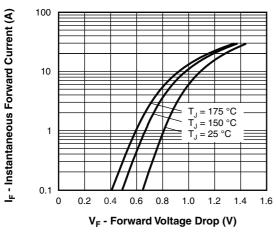


Fig. 1 - Typical Forward Voltage Drop Characteristics

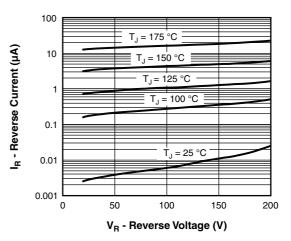


Fig. 2 - Typical Values of Reverse Current vs. Reverse Voltage

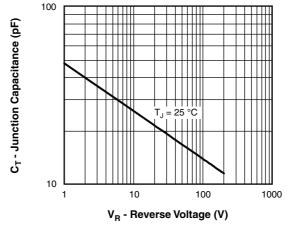


Fig. 3 - Typical Junction Capacitance vs. Reverse Voltage

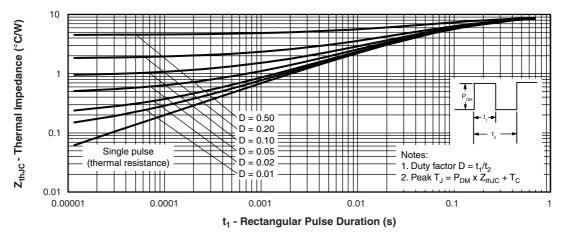


Fig. 4 - Maximum Thermal Impedance  $Z_{thJC}$  Characteristics

### VS-MURD620CTPbF

## Vishay Semiconductors

### Ultrafast Rectifier, 2 x 3 A FRED Pt®



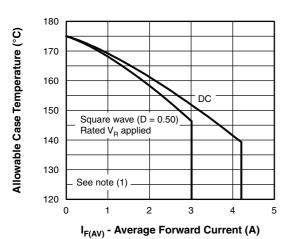
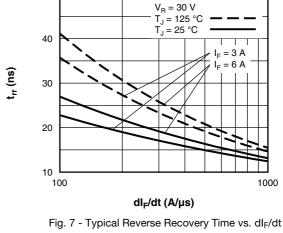


Fig. 5 - Maximum Allowable Case Temperature vs. Average Forward Current



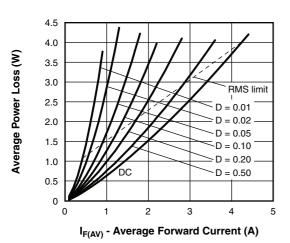


Fig. 6 - Forward Power Loss Characteristics

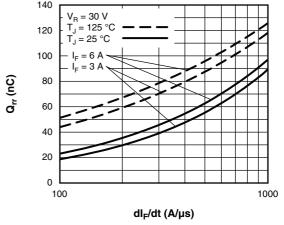


Fig. 8 - Typical Stored Charge vs. dl<sub>F</sub>/dt

#### Note



# Ultrafast Rectifier, 2 x 3 A FRED Pt®

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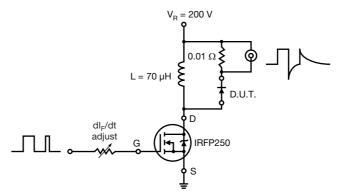
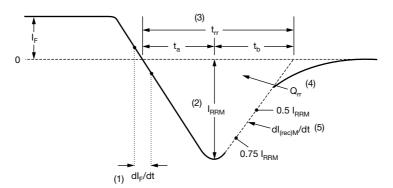


Fig. 9 - Reverse Recovery Parameter Test Circuit



- (1) dl<sub>F</sub>/dt rate of change of current through zero crossing
- (2) I<sub>RRM</sub> peak reverse recovery current
- (3)  $t_{rr}$  reverse recovery time measured from zero crossing point of negative going  $I_F$  to point where a line passing through 0.75  $I_{RRM}$  and 0.50  $I_{RRM}$  extrapolated to zero current.
- (4)  ${\rm Q_{rr}}$  area under curve defined by  ${\rm t_{rr}}$  and  ${\rm I_{RRM}}$

$$Q_{rr} = \frac{t_{rr} \times I_{RRM}}{2}$$

(5)  $dI_{(rec)M}/dt$  - peak rate of change of current during  $t_{\rm b}$  portion of  $t_{\rm rr}$ 

Fig. 10 - Reverse Recovery Waveform and Definitions

## **VS-MURD620CTPbF**

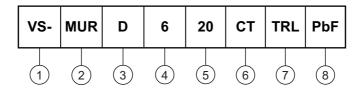
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### **ORDERING INFORMATION TABLE**

**Device code** 



1 - Vishay Semiconductors product

2 - Ultrafast MUR series

3 - D = D-PAK

4 - Current rating (6 = 6 A)

5 - Voltage rating (20 = 200 V)

TR = Tape and reel

TRL = Tape and reel (left oriented)
TRR = Tape and reel (right oriented)

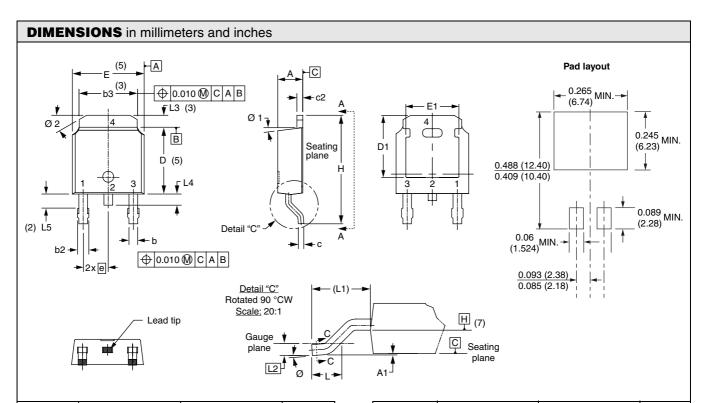
8 - PbF = Lead (Pb)-free

LINKS TO RELATED DOCUMENTS				
Dimensions <u>www.vishay.com/doc?95016</u>				
Part marking information	www.vishay.com/doc?95059			
Packaging information	www.vishay.com/doc?95033			



# Vishay High Power Products

# **D-PAK (TO-252AA)**



SYMBOL	MILLIM	MILLIMETERS INCHES		HES	NOTES
STIVIBUL	MIN.	MAX.	MIN.	MAX.	NOTES
Α	2.18	2.39	0.086	0.094	
A1	-	0.13	-	0.005	
b	0.64	0.89	0.025	0.035	
b2	0.76	1.14	0.030	0.045	
b3	4.95	5.46	0.195	0.215	3
С	0.46	0.61	0.018	0.024	
c2	0.46	0.89	0.018	0.035	
D	5.97	6.22	0.235	0.245	5
D1	5.21	1	0.205	-	3
Е	6.35	6.73	0.250	0.265	5
E1	4.32	-	0.170	-	3

SYMBOL	MILLIM	MILLIMETERS		INCHES		
STWIBOL	MIN.	MAX.	MIN.	MAX.	NOTES	
е	2.29	BSC	0.090	BSC		
Н	9.40	10.41	0.370	0.410		
L	1.40	1.78	0.055	0.070		
L1	2.74 BSC		0.108 REF.			
L2	0.51 BSC		0.020 BSC			
L3	0.89	1.27	0.035	0.050	3	
L4	-	1.02	-	0.040		
L5	1.14	1.52	0.045	0.060	2	
Ø	0°	10°	0°	10°		
Ø1	0°	15°	0°	15°		
Ø2	25°	35°	25°	35°		

### Notes

- (1) Dimensioning and tolerancing as per ASME Y14.5M-1994
- (2) Lead dimension uncontrolled in L5
- (3) Dimension D1, E1, L3 and b3 establish a minimum mounting surface for thermal pad
- (4) Section C C dimension apply to the flat section of the lead between 0.13 and 0.25 mm (0.005 and 0.10") from the lead tip
- (5) Dimension D, and E do not include mold flash. Mold flash shall not exceed 0.127 mm (0.005") per side. These dimensions are measured at the outermost extremes of the plastic body
- (6) Dimension b1 and c1 applied to base metal only
- $^{\left(7\right)}\,$  Datum A and B to be determined at datum plane H
- (8) Outline conforms to JEDEC outline TO-252AA

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## **Legal Disclaimer Notice**



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Please note that some Vishay documentation may still make reference to RoHS Directive 2002/95/EC. We confirm that all the products identified as being compliant to Directive 2002/95/EC conform to Directive 2011/65/EU.

Revision: 12-Mar-12 1 Document Number: 91000